# LITE ON SEMICONDUCTOR

### STPRA1010CT thru 1020CT

#### SUPER FAST **GLASS PASSIVATED RECTIFIERS**

REVERSE VOLTAGE - 100 to 200 Volts FORWARD CURRENT - 10 Amperes

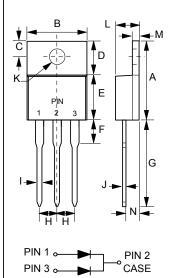
**TO-220AB** 

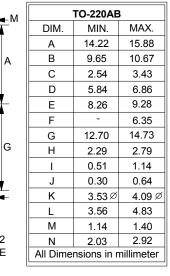
#### **FEATURES**

- Glass passivated chip
- Superfast switching time for high efficiency
- Low forward voltage drop and high current capability
- Low reverse leakage current
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- Soft recovery characteristic

#### **MECHANICAL DATA**

- Case : TO-220AB molded plastic
- Polarity : As marked on the body
- Weight : 0.08 ounces, 2.24 grams
- Mounting position : Any
- Max. mounting torque = 0.5 N.m (5.1 Kgf.cm)





#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

CHARACTERISTICS	SYMBOL	STPRA1010CT	STPRA1020CT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	100	200	V
Maximum RMS Voltage	VRMS	70	140	V
Maximum DC Blocking Voltage	VDC	100	200	V
Maximum Average Forward @Tc=110°C	l(AV)	10		А
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	IFSM	55		A
Maximum forward Voltage IF=5A@TJ=25°C   Pulse Width =300us IF=5A@TJ=125°C   Duty cycle IF=10A@TJ=25°C   IF=10A@TJ=25°C IF=10A@TJ=125°C	VF	1. 1.2	1.1 1.0 1.25 1.20	
$\begin{array}{llllllllllllllllllllllllllllllllllll$		50 600		uA
Typical Junction Capacitance per element (Note 1)	CJ	25		pF
Maximum Reverse Recovery Time (Note 2)	Trr	30		ns
Typical Thermal Resistance (Note 3)	Rθ JC	4.0		°C/W
Operating and Storage Temperature Range	TJ,TSTG	-55 to	+150	°C

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC. 2.Reverse Recovery Test Conditions:IF=0.5A,IR=1.0A,IRR 0.25A. REV. 3, Sep-2010, KTGC19

3.Device mounted on 75 mm x 75 mm x 2 mm Cu Plate.

## RATING AND CHARACTERISTIC CURVES STPRA1010CT thru STPRA1020CT

#### FIG.1 - FORWARD CURRENT DERATING CURVE FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT PEAK FORWARD SURGE CURRENT, AMPERES 12 60 AVERAGE FORWARD CURRENT AMPERES 10 50 8 40 30 6 20 4 2 10 RESISTIVE OR INDUCTIVE LOAD TP=8.3ms Single Half-Sine ine-vva. | | | | | 10 0∟ 25 0 75 100 2 5 50 50 125 150 175 20 100 NUMBER OF CYCLES AT 60Hz CASE TEMPERATURE ,°C FIG.4 - TYPICAL FORWARD CHARACTERISTICS FIG.3 - TYPICAL REVERSE CHARACTERISTICS 100 100 INSTANTANEOUS REVERSE CURRENT , (uA) TJ = 100℃ PERCENT OF FORWARD CURRENT, (A) 10 10 TJ = 75℃ 1 1 TJ = 25℃ T<sub>J</sub> =25℃ PULSE WIDTH 300us 0.1 0.1 0 20 40 60 80 100 120 0 0.2 0.4 0.6 0.8 1 1.2 INSTANTANEOUS FORWARD VOLTAGE, VOLTS PERCENT OF RATED PEAK REVERSE VOLTAGE (%) FIG.5 - TYPICAL JUNCTION CAPACITANCE 100 CAPACITANCE, (pF) 10 TJ = 25°C, f= 1MHz 1 0.1 10 100 1 **REVERSE VOLTAGE**, VOLTS

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